# NSN 5961-00-882-8511

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Inclosure Material:

Metal

**Overall Length:** 

0.350 inches

### **Overall Diameter:**

0.820 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

**Mounting Method:** 

# Unthreaded hole

Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

10.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector absolute

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

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